

View Online at https://aerobasegroup.com/nsn/5961-00-355-4793

## **Inclosure Material:**

Metal and plastic

## **Overall Length:**

Between 0.660 inches and 0.780 inches

## **Terminal Length:**

Between 0.100 inches and 0.155 inches

## **Overall Height:**

0.180 inches

## **Overall Width:**

Between 0.220 inches and 0.280 inches

## Component Name And Quantity:

4 transistor

## **Mounting Method:**

Terminal

## Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon all transistor

## Voltage Rating In Volts Per Characteristic:

70.0 collector to base voltage, dc all transistor and 45.0 collector to emitter voltage/static/base open all transistor and 70.0 collector to

emitter voltage, dc with base short-circuited to emitter all transistor and 6.0 emitter to base voltage, dc all transistor

## **Current Rating Per Characteristic:**

1.50 amperes source cutoff current all transistor

## **Power Rating Per Characteristic:**

2000.0 milliwatts small-signal input power, common-collector absolute all transistor

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

All transistor junction pattern arrangement: npn

## **Precious Material And Location:**

Terminal surface option gold

## **Precious Material:**

Gold

# Test Data Document:

07187-4006583 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Terminal Type And Quantity:**

14 pin

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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